

Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current (Note 6)	Steady State	T _A = +25°C	I _D	4.2	A
		T _A = +70°C		3.4	
Pulsed Drain Current (Note 7)			I _{DM}	27	A

Thermal Characteristics

Characteristic			Symbol	Value	Unit
Power Dissipation (Note 6)	T _A = +25°C		P _D	0.8	W
	T _A = +70°C			0.5	
Thermal Resistance, Junction to Ambient @T _A = +25°C			R _{θJA}	156	°C/W
Operating and Storage Temperature Range			T _J , T _{STG}	-55 to +150	°C

Notes: 6. Device mounted on FR-4 PCB, with minimum recommended pad layout.
7. Repetitive rating, pulse width limited by junction temperature.

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	20	–	–	V	V _{GS} = 0V, I _D = 10μA
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	–	–	1.0	μA	V _{DS} = 20V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	–	–	±100	nA	V _{GS} = ±8V, V _{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(th)}	0.4	–	1.0	V	V _{DS} = V _{GS} , I _D = 50μA
Static Drain-Source On-Resistance	R _{DS(on)}	–	–	90	mΩ	V _{GS} = 4.5V, I _D = 3.6A
				120		V _{GS} = 2.5V, I _D = 3.1A
Forward Transfer Admittance	Y _{fs}	–	13	–	S	V _{DS} = 5V, I _D = 3.6A
Diode Forward Voltage	V _{SD}	–	0.75	1.0	V	V _{GS} = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	–	594.3	–	pF	V _{DS} = 10V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	–	64.5	–	pF	
Reverse Transfer Capacitance	C _{rss}	–	57.7	–	pF	
Gate Resistance	R _g	–	1.5	–	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge	Q _g	–	7.0	–	nC	V _{GS} = 4.5V, V _{DS} = 10V, I _D = 3.6A
Gate-Source Charge	Q _{gs}	–	0.9	–	nC	
Gate-Drain Charge	Q _{gd}	–	1.4	–	nC	
Turn-On Delay Time	t _{D(on)}	–	7.4	–	ns	V _{DD} = 10V, V _{GS} = 4.5V, R _L = 2.78Ω, R _G = 1.0Ω
Turn-On Rise Time	t _r	–	9.8	–	ns	
Turn-Off Delay Time	t _{D(off)}	–	28.1	–	ns	
Turn-Off Fall Time	t _f	–	6.7	–	ns	

Notes: 8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to production testing.

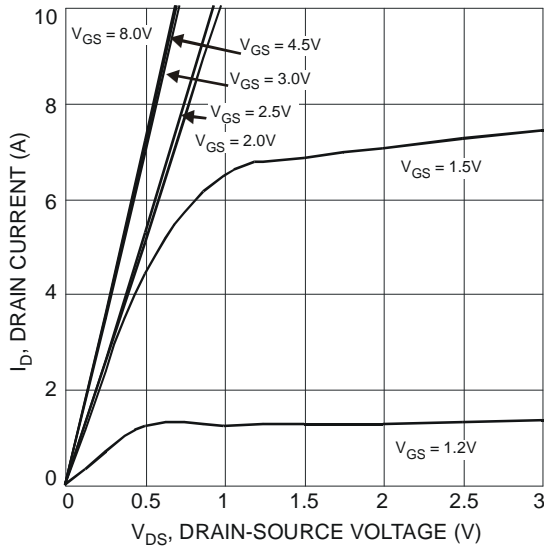


Fig. 1 Typical Output Characteristics

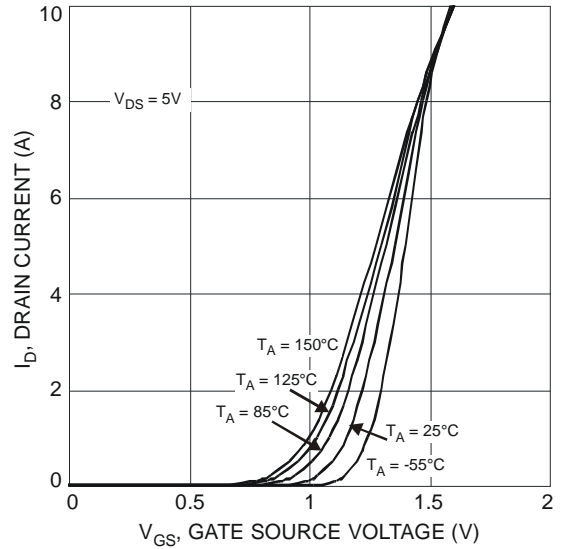


Fig. 2 Typical Transfer Characteristics

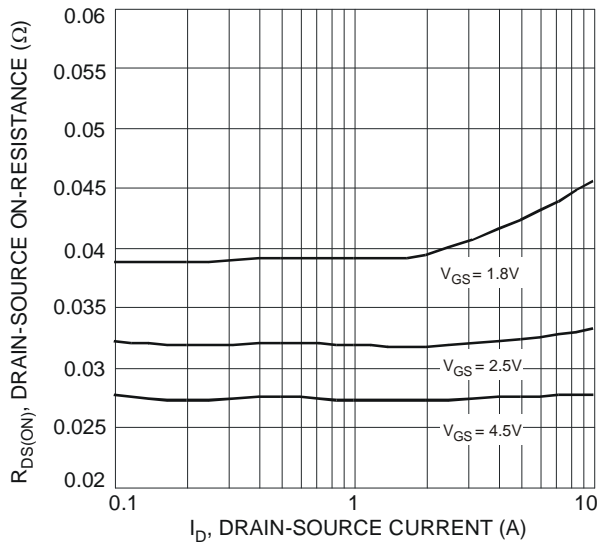


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

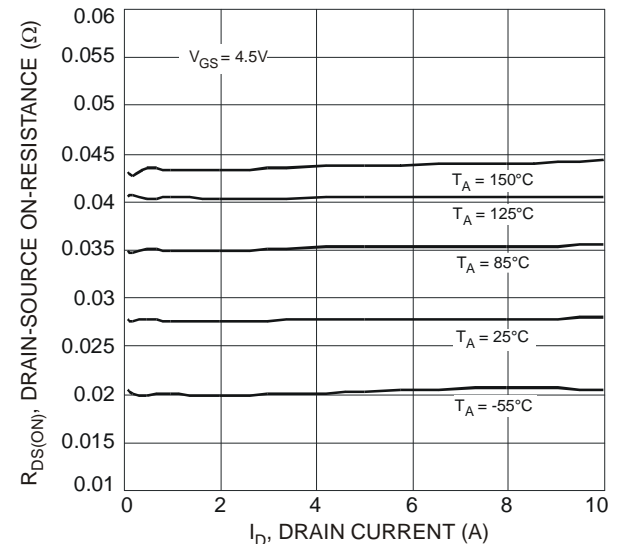


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature

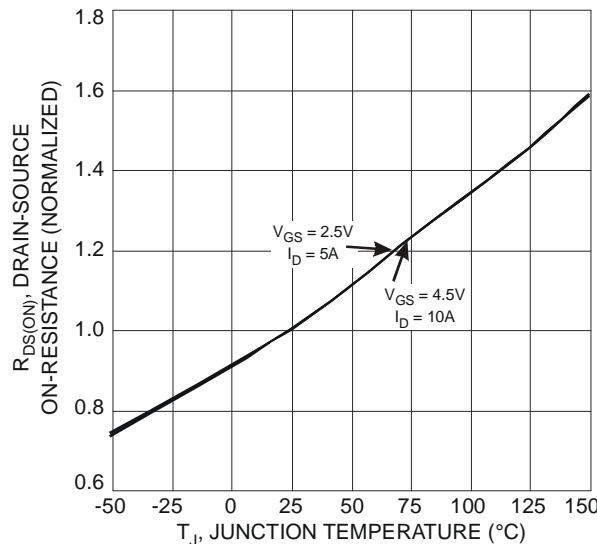


Fig. 5 On-Resistance Variation with Temperature

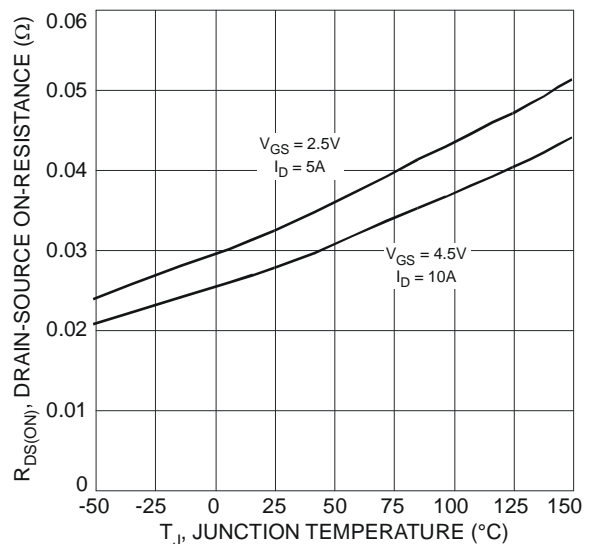


Fig. 6 On-Resistance Variation with Temperature

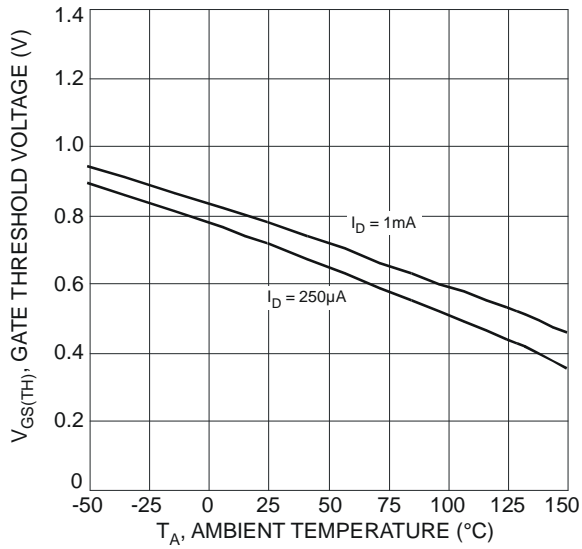


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

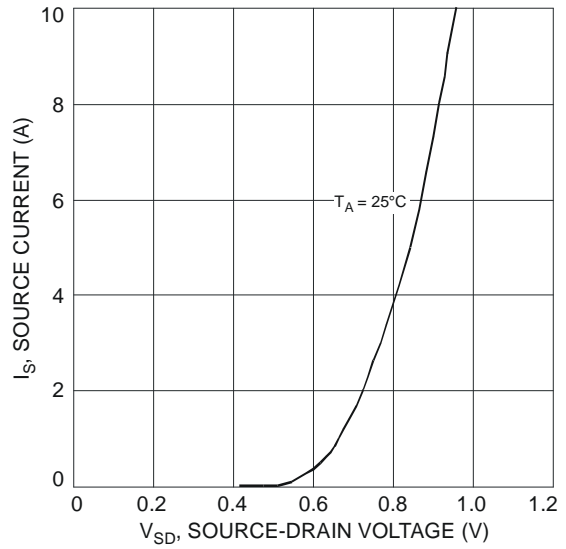


Fig. 8 Diode Forward Voltage vs. Current

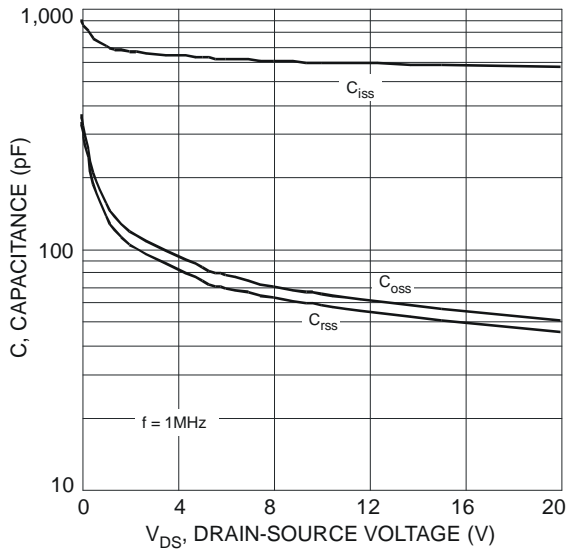


Fig. 9 Typical Capacitance

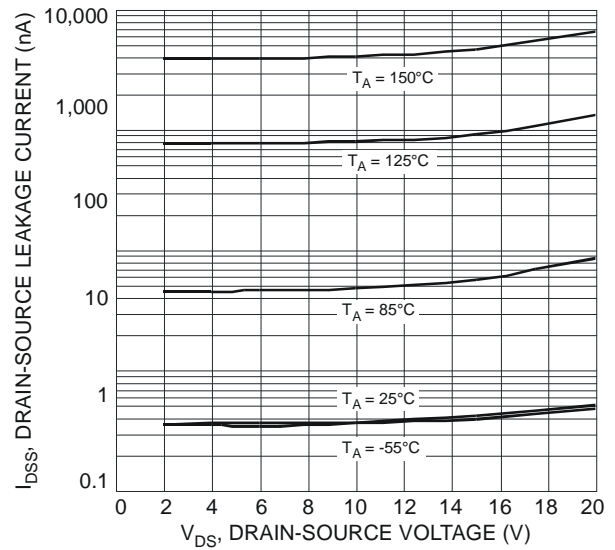


Fig. 10 Typical Drain-Source Leakage Current vs. Drain-Source Voltage

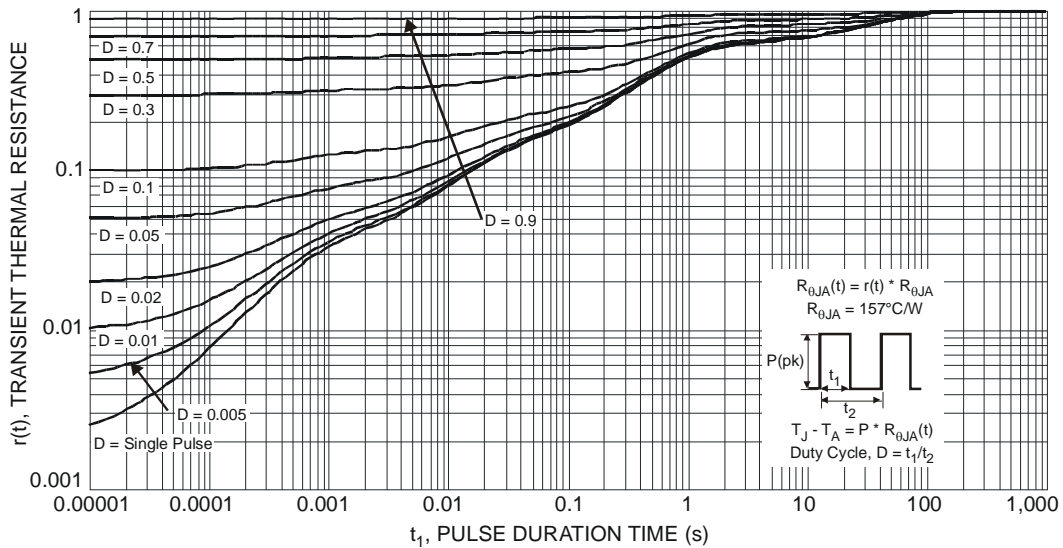
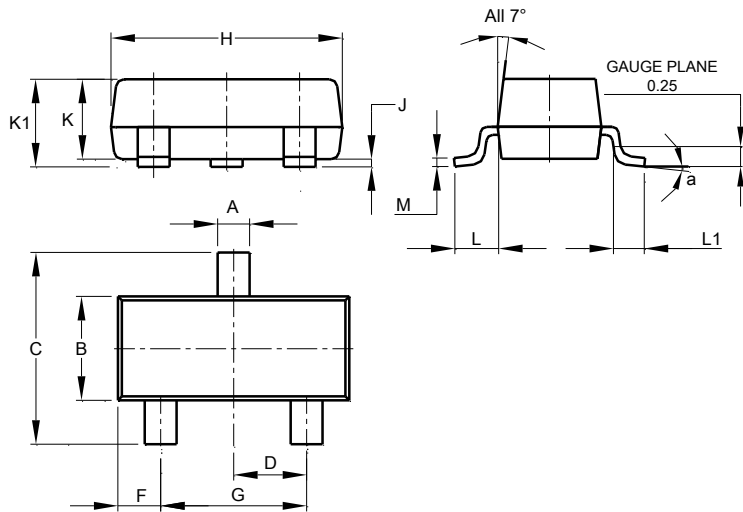


Fig. 11 Transient Thermal Response

Package Outline Dimensions

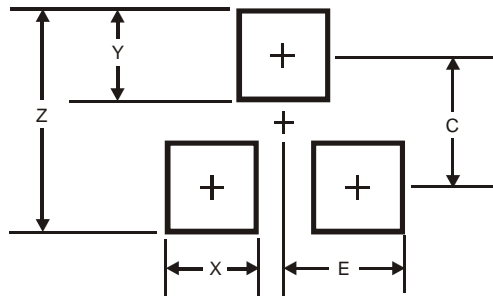
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
α	8°		
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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